CMOS Digital Integrated Circuits Silicon Monolithic

# 74LCX86FT

#### 1. Functional Description

Low-Voltage Quad 2-Input Exclusive-OR Gate with 5-V Tolerant Inputs and Outputs

#### 2. General

The 74LCX86FT is a high-performance CMOS exclusive OR gate. Designed for use in 3.3 V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

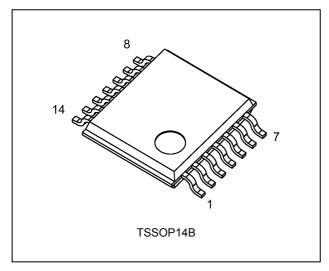
The device is designed for low-voltage (3.3 V)  $V_{CC}$  applications, but it could be used to interface to 5 V supply environment for inputs.

All inputs are equipped with protection circuits against static discharge.

#### 3. Features

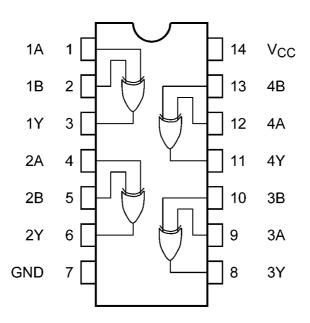
- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C
- (3) Low-voltage operation:  $V_{CC} = 1.65$  to 3.6 V
- (4) High-speed operation:  $t_{pd}$  = 7.5 ns (max) (V<sub>CC</sub> = 3.3 ± 0.3 V)
- (5) Output current:  $|I_{OH}|/I_{OL} = 24 \text{ mA} (\text{min}) (V_{CC} = 3.0 \text{ V})$
- (6) Power-down protection provided on all inputs and outputs
- (7) Pin and function compatible with the 74 series(74LVC/ALVC etc.) 86 type
- Note1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

#### 4. Packaging

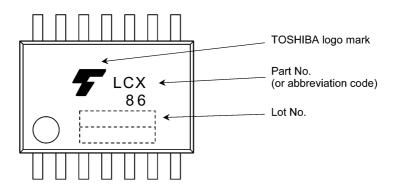


### 5. Pin Assignment

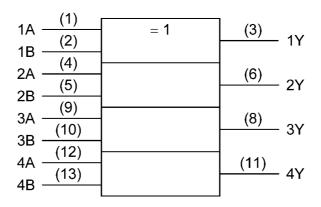
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#### 6. Marking



7. IEC Logic Symbol



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#### 8. Truth Table

Inputs A	Inputs B	Outputs Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	L

#### 9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 6.5	V
Input voltage	V <sub>IN</sub>		-0.5 to 6.5	V
Output voltage	V <sub>OUT</sub>	(Note 1)	-0.5 to 6.5	V
		(Note 2)	-0.5 to V <sub>CC</sub> + 0.5	
Input diode current	I <sub>IK</sub>		-50	mA
Output diode current	I <sub>ОК</sub>	(Note 3)	±50	mA
Output current	Ι <sub>ουτ</sub>		±50	mA
Power dissipation	PD	(Note 4)	180	mW
V <sub>CC</sub> /ground current	I <sub>CC</sub> /I <sub>GND</sub>		±100	mA
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC}$  = 0 V

Note 2: High or low state.  $I_{OUT}$  absolute maximum rating must be observed.

Note 3:  $V_{OUT}$  < GND,  $V_{OUT}$  >  $V_{CC}$ 

Note 4: 180 mW in the range of  $T_a = -40$  to 85 °C. From  $T_a = 85$  to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

#### 10. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		1.65 to 3.6	V
		(Note 1)	1.5 to 3.6	
Input voltage	V <sub>IN</sub>		0 to 5.5	V
Output voltage	V <sub>OUT</sub>	(Note 2)	0 to 5.5	V
		(Note 3)	0 to V <sub>CC</sub>	
Output current	I <sub>OH</sub> ,I <sub>OL</sub>	(Note 4)	±24	mA
		(Note 5)	±12	
Operating temperature	T <sub>opr</sub>		-40 to 125	°C
Input rise and fall times	dt/dv	(Note 6)	0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1: Data retention only

Note 2:  $V_{CC}$  = 0 V

Note 3: High or low state

Note 4:  $V_{CC}$  = 3.0 to 3.6 V

Note 5:  $V_{CC}$  = 2.7 to 3.0 V

Note 6:  $V_{IN}$  = 0.8 to 2.0 V,  $V_{CC}$  = 3.0 V

#### **11. Electrical Characteristics**

#### 11.1. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		1.65 to 2.3	$V_{CC} \times 0.9$	—	V
				2.3 to 2.7	1.7	_	1
				2.7 to 3.6	2.0	_	]
Low-level input voltage	VIL	—		1.65 to 2.3	_	$V_{CC} \times 0.1$	V
				2.3 to 2.7	_	0.7	]
				2.7 to 3.6	_	0.8	]
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OH</sub> = -100 μA	1.65 to 3.6	V <sub>CC</sub> - 0.2	_	V
			I <sub>OH</sub> = -4 mA	1.65	1.05	_	]
			I <sub>OH</sub> = -8 mA	2.3	1.7	_	]
			I <sub>OH</sub> = -12 mA	2.7	2.2	_	1
			I <sub>OH</sub> = -18 mA	3.0	2.4	_	]
			I <sub>OH</sub> = -24 mA	3.0	2.2	_	]
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	1.65 to 3.6	_	0.2	V
			I <sub>OL</sub> = 4 mA	1.65	_	0.45	]
			I <sub>OL</sub> = 8 mA	2.3	_	0.7	]
			I <sub>OL</sub> = 12 mA	2.7	_	0.4	1
			I <sub>OL</sub> = 16 mA	3.0	_	0.4	1
			I <sub>OL</sub> = 24 mA	3.0	_	0.55	]
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5 V		1.65 to 3.6	_	±5.0	μA
Power-OFF leakage current	I <sub>OFF</sub>	V <sub>IN</sub> /V <sub>OUT</sub> = 5.5 V		0	_	10.0	μΑ
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND		1.65 to 3.6	_	10.0	μA
		V <sub>IN</sub> = 3.6 to 5.5 V		1.65 to 3.6	_	±10.0	]
Quiescent supply current	Δl <sub>CC</sub>	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V (per 1 input)		2.7 to 3.6		500	μA

#### 11.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Test Cond	dition	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	—		1.65 to 2.3	$V_{CC} \times 0.9$	—	V
				2.3 to 2.7	1.7	—	
				2.7 to 3.6	2.0	—	
Low-level input voltage	VIL	—		1.65 to 2.3	_	$V_{CC} \times 0.1$	V
				2.3 to 2.7	—	0.7	
				2.7 to 3.6	—	0.8	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OH</sub> = -100 μA	1.65 to 3.6	V <sub>CC</sub> - 0.2	—	V
			I <sub>OH</sub> = -4 mA	1.65	0.9	—	
			I <sub>OH</sub> = -8 mA	2.3	1.55	—	
			I <sub>OH</sub> = -12 mA	2.7	2.0	—	
			I <sub>OH</sub> = -18 mA	3.0	2.2	—	
			I <sub>OH</sub> = -24 mA	3.0	2.0	—	
Low-level output voltage	V <sub>OL</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OL</sub> = 100 μA	1.65 to 3.6	_	0.2	V
			I <sub>OL</sub> = 4 mA	1.65	_	0.65	
			I <sub>OL</sub> = 8 mA	2.3	_	0.9	
			I <sub>OL</sub> = 12 mA	2.7	—	0.6	
			I <sub>OL</sub> = 16 mA	3.0	—	0.6	
			I <sub>OL</sub> = 24 mA	3.0	—	0.75	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5 V		1.65 to 3.6	—	±20.0	μA
Power-OFF leakage current	I <sub>OFF</sub>	V <sub>IN</sub> /V <sub>OUT</sub> = 5.5 V		0	_	40.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		1.65 to 3.6		40.0	μA
		V <sub>IN</sub> = 3.6 to 5.5 V		1.65 to 3.6	_	±40.0	
Quiescent supply current	Δl <sub>CC</sub>	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V (per 1 input)		2.7 to 3.6	—	5.0	mA

#### 11.3. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		See 11.7 AC Test Circuit,	$1.8\pm0.15$	_	35.0	ns
			Fig. 11.8.1, Table 11.8.1	$2.5\pm0.2$	_	10.0	
				2.7	_	7.0	1
				$3.3\pm0.3$	1.5	6.5	
Output skew	t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	_	2.7	_	—	ns
				$3.3\pm0.3$	_	1.0	1

Note 1: Parameter guaranteed by design. ( $t_{osLH} = |t_{PLH}m-t_{PLH}n|$ ,  $t_{osHL} = |t_{PHL}m-t_{PHL}n|$ )

#### 11.4. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		See 11.7 AC Test Circuit,	$1.8\pm0.15$	_	38.5	ns
			Fig. 11.8.1, Table 11.8.1	$2.5\pm0.2$	_	11.0	
				2.7	_	8.0	
				$\textbf{3.3}\pm\textbf{0.3}$	1.5	7.5	
Output skew	t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	—	2.7	_	—	ns
				$3.3\pm0.3$	_	1.0	

Note 1: Parameter guaranteed by design. ( $t_{osLH} = |t_{PLH}m-t_{PLH}n|$ ,  $t_{osHL} = |t_{PHL}m-t_{PHL}n|$ )

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Unit V

V

#### 11.5. Dynamic Switching Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500$ $\Omega$ )

52)				
Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.
Quiet output maximum dynamic $V_{OL}$	V <sub>OLP</sub>	V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	3.3	0.8
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	3.3	0.8

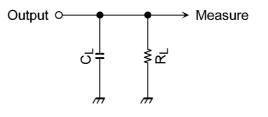
#### 11.6. Capacitive Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Input capacitance	C <sub>IN</sub>		_	3.3	7	pF
Output capacitance	C <sub>OUT</sub>		_	0	8	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 1)	f <sub>IN</sub> =10 MHz	3.3	25	pF

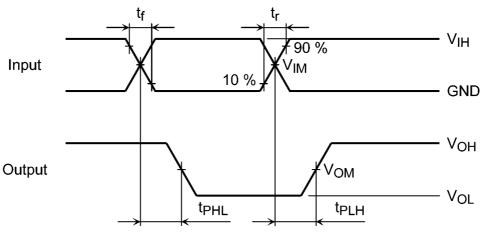
Note 1: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

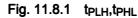
 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$  (per 1 gate)

#### 11.7. AC Test Circuit



#### 11.8. AC Waveform





#### Table 11.8.1 AC Waveform Symbols

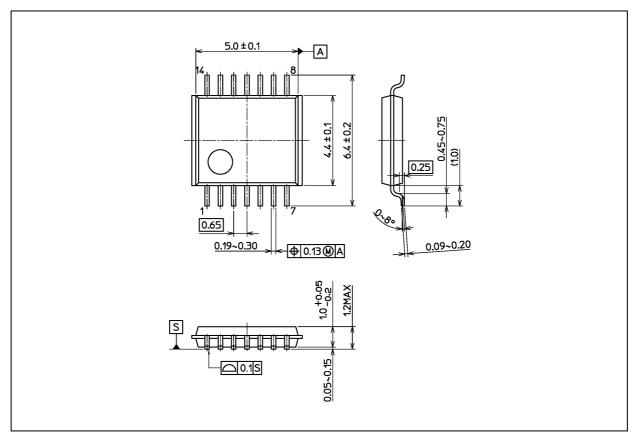
	Symbol	$V_{CC}$ = 3.3 ± 0.3 V $V_{CC}$ = 2.7 V	$V_{CC}$ = 2.5 $\pm$ 0.2 V	$V_{CC}$ = 1.8 $\pm$ 0.15 V
Input	V <sub>IH</sub>	2.7 V	V <sub>CC</sub>	V <sub>CC</sub>
	V <sub>IM</sub>	1.5 V	V <sub>CC</sub> /2	V <sub>CC</sub> /2
	t <sub>r</sub> , t <sub>f</sub>	2.5 ns	2.0 ns	2.0 ns
Output	V <sub>OM</sub>	1.5 V	V <sub>OH</sub> /2	V <sub>OH</sub> /2
Load	CL	50 pF	30 pF	30 pF
	RL	500 Ω	500 Ω	1 kΩ



### 74LCX86FT

#### **Package Dimensions**

Unit: mm



Weight: 0.054 g (typ.)

	Package Name(s)
Nickname: TSSOP14B	

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